



# **DMP2012SN**

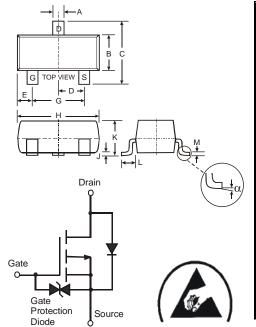
#### P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Lead Free By Design/RoHS Compliant (Note 2)
- **ESD Protected Gate**
- "Green" Device (Note 4)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SC-59
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: See Last Page
- Ordering & Date Code Information: See Last Page
- Weight: 0.008 grams (approximate)



SC-59									
Dim	Min	Max							
Α	0.30	0.50							
В	1.40	1.80							
С	2.50	3.00							
D	0.85	1.05							
E	0.30	0.70							
G	1.70	2.10							
H	2.70	3.10							
7		0.10							
K	1.00	1.40							
L	0.55	0.70							
М	0.10	0.35							
α	0°	8°							
All Dimensions in mm									

**EQUIVALENT CIRCUIT** 

**ESD** protected

### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	-20	V	
Gate-Source Voltage	V <sub>GSS</sub>	±12	V	
Drain Current (Note 1) Steady State	I <sub>D</sub>	-0.7	Α	
Pulsed Drain Current (Note 3)	I <sub>DM</sub>	-2.8	Α	
Total Power Dissipation (Note 1)	P <sub>d</sub>	500	mW	
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	250	°C/W	
Operating and Storage Temperature Range	T <sub>i</sub> , T <sub>STG</sub>	-65 to +150	°C	

Notes:

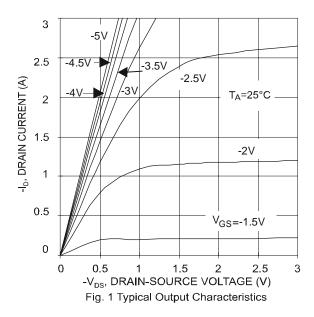
- Device mounted on FR-4 PCB. 1.
- 2. No purposefully added lead.
- Pulse width ≤10μS, Duty Cycle ≤1%.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

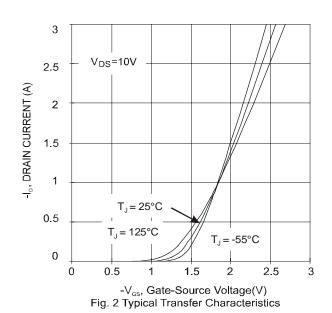


# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition				
OFF CHARACTERISTICS (Note 5)										
Drain-Source Breakdown Voltage		-20	_		V	$V_{GS} = 0V, I_D = 250mA$				
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-10	μА	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V				
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±10	μА	$V_{GS} = \pm 12V, V_{DS} = 0V$				
ON CHARACTERISTICS (Note 5)			•	•	•					
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.5	_	-1.2	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$				
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	_	0.23 0.37	0.30 0.50	Ω	$V_{GS} = -4.5V$ , $I_D = -0.4A$ $V_{GS} = -2.5V$ , $I_D = -0.4A$				
Forward Transfer Admittance	Y <sub>fs</sub>	_	1.5		S	$V_{DS} = -10V, I_D = 0.4A$				
Diode Forward Voltage (Note 5)	V <sub>SD</sub>	_	-0.8	-1.1	$V = V_{GS} = 0V, I_S = -0.7A$					
DYNAMIC CHARACTERISTICS			•	•	•	•				
Input Capacitance	C <sub>iss</sub>	_	180		pF					
Output Capacitance	C <sub>oss</sub>	_	120	_	pF	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1.0MHz				
Reverse Transfer Capacitance	C <sub>rss</sub>	_	50		pF	II — I.OIVII IZ				
SWITCHING CHARACTERISTICS			_							
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5		ns					
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	55		ns	$V_{DD} = -10V, I_{D} = -0.4A,$ $V_{GS} = -5.0V, R_{GEN} = 50\Omega$				
Turn-On Rise Time	t <sub>r</sub>		20		ns					
Turn-Off Fall Time	t <sub>f</sub>		70	_	ns					

Notes: 5. Short duration test pulse used to minimize self-heating effect.







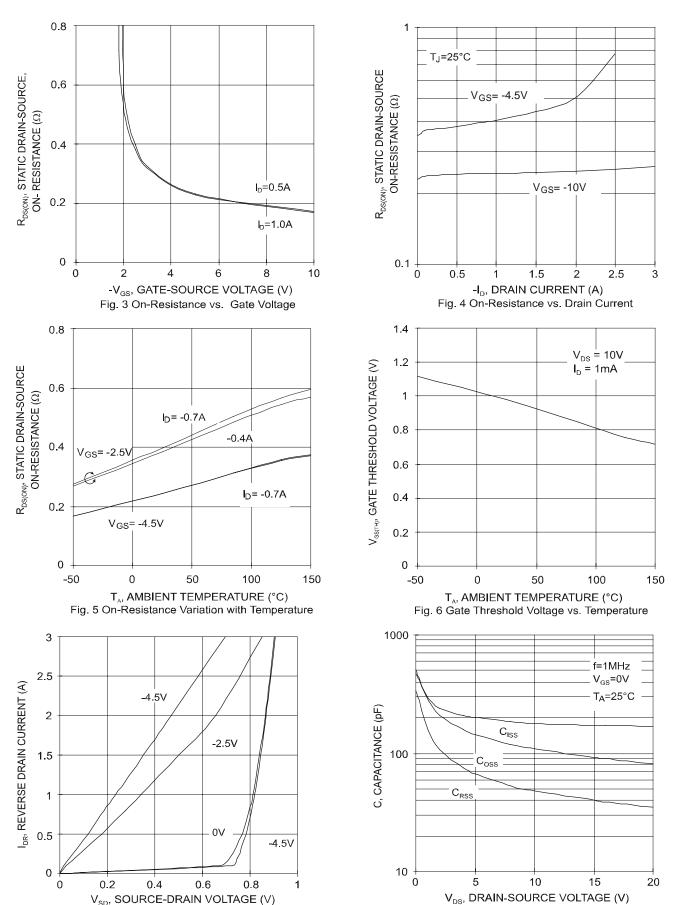


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

Fig. 8: Typical Junction Capacitance

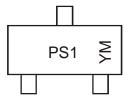


# Ordering Information (Note 6)

Device	Packaging	Shipping
DMP2012SN-7	SC-59	3000/Tape & Reel

Notes: 6. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



PS1 = Product Type Marking Code

YM = Date Code Marking

Y = Year ex: T = 2006

M = Month ex: 9 = September

#### Date Code Key

Year	2006 200		2007		2008		2009			2011	2012	
Code	Т		U		V W		X		Υ		Z	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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